

SEMICONDUCTOR TECHNICAL DATA

1N4007

General Purpose Plastic Rectifier

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0.
- \cdot Construction utilizes void-free molded plastic technique.
- \cdot Low reverse leakage.
- · High forward surge capability.
- High temperature soldering guaranteed: 250 °C/10 seconds, 0.375 (9.5mm) lead length, 5 Ibs. (2.3kg) tension.
- \cdot Tj is 150 °C(Max.) and Tstg is 175 °C(Max.) with PI glue

APPLICATIONS

- \cdot General purpose rectification of power supply application
- \cdot Consumer & automotive application

MAXIMUM RATING (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Repetitive Peak Reverse Voltage	V _{RRM}	1000	V
RMS Voltage	V _{RMS}	700	V
DC Blocking Voltage	V _{DC}	V _{DC} 1000	
Average Forward Rectified Current	I _{F(AV)} *	1	А
Peak forward surge current 8.3mS single			
half sine-wave superimposed on rated	I _{FSM}	30	А
load (JEDEC Method) Ta=50 °C			
Operation Junction	Tj	-55~125	ĉ
Storage Temperature Range	T _{stg}	-55~150	ĉ

* 0.375 (9.5mm) lead length at Ta= 50 $^{\circ}\mathrm{C}$

ELECTRICAL CHARACTERISTICS (Ta=25 °C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Forward Voltage	V _F	I _F =1A	-	-	1.1	V
Leakage Current	I _R	V _{RRM} =1000V	-	-	5.0	μA
		V _{RRM} =1000V, Ta=100 °C	-	-	50	
Reverse Recovery Time	t _{rr}	I _{FM} =20mA, I _{FM} =1mA	-	1.0	-	μs
Junction Capacitance	Cj	V _{RM} =4.0V, f=1MHz	-	15	-	pF
Thermal Resistance —	R _{th(j-a)}	Junction to ambient	-	50	-	°C/W
	R _{th(j-1)}	Junction to lead	-	25	-	

Note 1) Thermal resistance from junction to ambient at 0.375 (9.5mm) lead length P.C.B mounted.



Marking





 I_F - V_F



FORWARD VOLTAGE $V_F(V)$





REVERSE VOLTAGE $V_R(V)$



NUMBER OF CYCLES AT 60Hz

TYPICAL REVERSE CHARACTERISTICS



PERCENTAGE OF PEAK REVERSE VOLTAGE (%)

 r_{th} - t_w

PULSE DURATION $t_w(s)$